

SKiiP 24NAB176V1



MiniSKiiP® 2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter

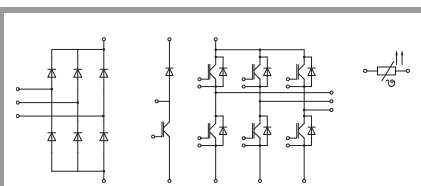
SKiiP 24NAB176V1

Features*

- Trench IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532
- NTC T-Sensor

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 125^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +125^\circ\text{C}$)
- $I_{t(RMS)}$ limited to 20A for +B, B, -B, -DC/U, -DC/V, -DC/W power connectors
- The distance between terminals of temperature sensor and -DC/W is not sufficient for basic insulation
- The distance between terminals of +rect, +B and +DC not sufficient for basic insulation
- The distance between terminals of -B, -DC/U, DC/V and -DC/W not sufficient for basic insulation



NAB

| Absolute Maximum Ratings | | | | |
|-----------------------------|---|---------------------------|-------------|------------------|
| Symbol | Conditions | | Values | Unit |
| Inverter - IGBT | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | | 1700 | V |
| I_C | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 38 | A |
| | | $T_j = 150^\circ\text{C}$ | 29 | A |
| I_C | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 43 | A |
| | | $T_j = 150^\circ\text{C}$ | 33 | A |
| I_{Cnom} | | | 29 | A |
| I_{CRM} | | | 58 | A |
| V_{GES} | | | -20 ... 20 | V |
| t_{psc} | $V_{CC} = 1200\text{ V}$ | $T_j = 125^\circ\text{C}$ | 10 | μs |
| | $V_{GE} \leq 20\text{ V}$ | | | |
| | $V_{CES} \leq 1700\text{ V}$ | | | |
| T_j | | | -55 ... 150 | $^\circ\text{C}$ |
| Chopper - IGBT | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | | 1700 | V |
| I_C | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 38 | A |
| | | $T_j = 150^\circ\text{C}$ | 29 | A |
| I_C | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 43 | A |
| | | $T_j = 150^\circ\text{C}$ | 33 | A |
| I_{Cnom} | | | 29 | A |
| I_{CRM} | | | 58 | A |
| V_{GES} | | | -20 ... 20 | V |
| t_{psc} | $V_{CC} = 1200\text{ V}$ | $T_j = 125^\circ\text{C}$ | 10 | μs |
| | $V_{GE} \leq 20\text{ V}$ | | | |
| | $V_{CES} \leq 1700\text{ V}$ | | | |
| T_j | | | -55 ... 150 | $^\circ\text{C}$ |
| Inverse - Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | | 1700 | V |
| I_F | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 48 | A |
| | | $T_j = 175^\circ\text{C}$ | 38 | A |
| I_F | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 54 | A |
| | | $T_j = 175^\circ\text{C}$ | 43 | A |
| I_{FRM} | | | 80 | A |
| I_{FSM} | $t_p = 10\text{ ms, sin } 180^\circ, T_j = 150^\circ\text{C}$ | | 280 | A |
| T_j | | | -40 ... 175 | $^\circ\text{C}$ |
| Freewheeling - Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | | 1700 | V |
| I_F | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 48 | A |
| | | $T_j = 175^\circ\text{C}$ | 38 | A |
| I_F | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 54 | A |
| | | $T_j = 175^\circ\text{C}$ | 43 | A |
| I_{FRM} | | | 80 | A |
| I_{FSM} | $t_p = 10\text{ ms, sin } 180^\circ, T_j = 150^\circ\text{C}$ | | 280 | A |
| T_j | | | -40 ... 175 | $^\circ\text{C}$ |

SKiiP 24NAB176V1



MiniSKiiP® 2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter

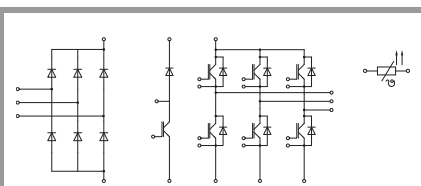
SKiiP 24NAB176V1

Features*

- Trench IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532
- NTC T-Sensor

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 125^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +125^\circ\text{C}$)
- $I_{t(RMS)}$ limited to 20A for +B, B, -B, -DC/-DC/U, -DC/V, -DC/W power connectors
- The distance between terminals of temperature sensor and -DC/W is not sufficient for basic insulation
- The distance between terminals of +rect, +B and +DC not sufficient for basic insulation
- The distance between terminals of -B, -DC/U, DC/V and -DC/W not sufficient for basic insulation



NAB

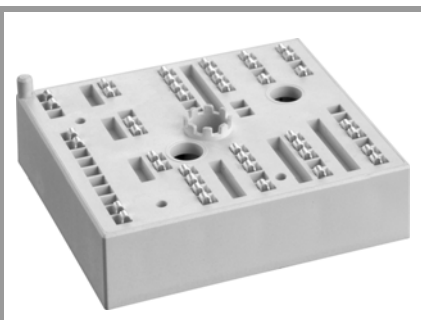
Absolute Maximum Ratings

| Symbol | Conditions | Values | Unit | |
|--------------------------|---|---------------------------|------|------------------|
| Rectifier - Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | 1800 | V | |
| I_F | $\lambda_{paste}=0.8 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 59 | A |
| | $T_j = 150^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 42 | A |
| I_F | $\lambda_{paste}=2.5 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 66 | A |
| | $T_j = 150^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 48 | A |
| I_{FSM} | $t_p = 10 \text{ ms}$ | $T_j = 25^\circ\text{C}$ | 370 | A |
| | sin 180° | $T_j = 150^\circ\text{C}$ | 270 | A |
| i^2t | $t_p = 10 \text{ ms}$ | $T_j = 25^\circ\text{C}$ | 685 | A ² s |
| | sin 180° | $T_j = 150^\circ\text{C}$ | 365 | A ² s |
| T_j | | -40 ... 150 | °C | |
| Module | | | | |
| $I_{t(RMS)}$ | $T_{terminal} = 80^\circ\text{C}$, 20 A per spring | 40 | A | |
| T_{stg} | module without TIM | -40 ... 125 | °C | |
| V_{isol} | AC sinus 50 Hz, 1 min | 2500 | V | |

Characteristics

| Symbol | Conditions | min. | typ. | max. | Unit |
|------------------------|---|---------------------------|------|------|------|
| Inverter - IGBT | | | | | |
| $V_{CE(sat)}$ | $I_C = 29 \text{ A}$ $V_{GE} = 15 \text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | 2.00 | 2.45 | V |
| | | $T_j = 125^\circ\text{C}$ | 2.45 | 2.90 | V |
| V_{CE0} | chipelevel | $T_j = 25^\circ\text{C}$ | 1.00 | 1.20 | V |
| | | $T_j = 125^\circ\text{C}$ | 0.90 | 1.10 | V |
| r_{CE} | $V_{GE} = 15 \text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | 34 | 43 | mΩ |
| | | $T_j = 125^\circ\text{C}$ | 53 | 62 | mΩ |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}$, $I_C = 1.2 \text{ mA}$ | 5.2 | 5.8 | 6.4 | V |
| I_{CES} | $V_{GE} = 0 \text{ V}$, $V_{CE} = 1700 \text{ V}$, $T_j = 25^\circ\text{C}$ | | | 0.3 | mA |
| C_{ies} | $V_{CE} = 25 \text{ V}$ $V_{GE} = 0 \text{ V}$ | $f = 1 \text{ MHz}$ | 2.50 | | nF |
| C_{oes} | | $f = 1 \text{ MHz}$ | 0.11 | | nF |
| C_{res} | | $f = 1 \text{ MHz}$ | 0.08 | | nF |
| Q_G | $V_{GE} = -8 \text{ V} \dots +15 \text{ V}$ | | 240 | | nC |
| R_{Gint} | $T_j = 25^\circ\text{C}$ | | 32 | | Ω |
| $t_{d(on)}$ | $V_{CC} = 900 \text{ V}$ $I_C = 20 \text{ A}$ | $T_j = 125^\circ\text{C}$ | 290 | | ns |
| t_r | | $T_j = 125^\circ\text{C}$ | 40 | | ns |
| E_{on} | $R_{G on} = 1 \Omega$ $R_{G off} = 1 \Omega$ | $T_j = 125^\circ\text{C}$ | 5.1 | | mJ |
| $t_{d(off)}$ | $di/dt_{on} = 580 \text{ A}/\mu\text{s}$ | $T_j = 125^\circ\text{C}$ | 690 | | ns |
| t_f | $di/dt_{off} = 120 \text{ A}/\mu\text{s}$ $dv/dt = 4000 \text{ V}/\mu\text{s}$ | $T_j = 125^\circ\text{C}$ | 120 | | ns |
| E_{off} | $V_{GE} = +15/-15 \text{ V}$ $L_s = 47 \text{ nH}$ | $T_j = 125^\circ\text{C}$ | 6.3 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=0.8 \text{ W/(mK)}$ | | 0.91 | | K/W |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=2.5 \text{ W/(mK)}$ | | 0.73 | | K/W |

SKiIP 24NAB176V1



MiniSKiIP® 2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter

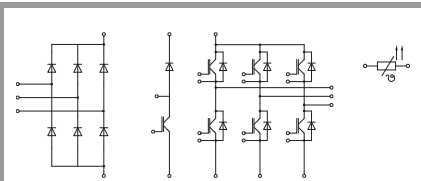
SKiIP 24NAB176V1

Features*

- Trench IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532
- NTC T-Sensor

Remarks

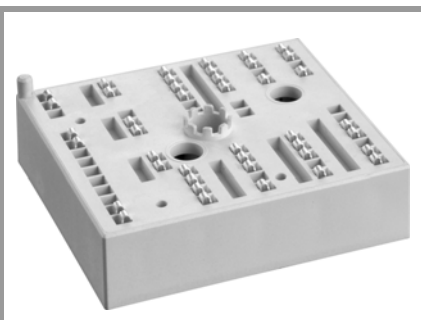
- Max. case temperature limited to $T_C=125^{\circ}\text{C}$
- Product reliability results valid for $T_j \leq 125^{\circ}\text{C}$ (recommended $T_{j,op} = -40 \dots +125^{\circ}\text{C}$)
- $I_{t(RMS)}$ limited to 20A for +B, B, -B, -DC/U, -DC/V, -DC/W power connectors
- The distance between terminals of temperature sensor and -DC/W is not sufficient for basic insulation
- The distance between terminals of +rect, +B and +DC not sufficient for basic insulation
- The distance between terminals of -B, -DC/U, DC/V and -DC/W not sufficient for basic insulation



NAB

| Characteristics | | | | | | |
|-----------------------------|---|-----------------------------|------|------|------|------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Chopper - IGBT | | | | | | |
| $V_{CE(sat)}$ | $I_C = 29\text{ A}$ $V_{GE} = 15\text{ V}$ chipllevel | $T_j = 25^{\circ}\text{C}$ | | 2.00 | 2.45 | V |
| | | $T_j = 125^{\circ}\text{C}$ | | 2.45 | 2.90 | V |
| V_{CE0} | chipllevel | $T_j = 25^{\circ}\text{C}$ | | 1.00 | 1.20 | V |
| | | $T_j = 125^{\circ}\text{C}$ | | 0.90 | 1.10 | V |
| r_{CE} | $V_{GE} = 15\text{ V}$ chipllevel | $T_j = 25^{\circ}\text{C}$ | | 34 | 43 | mΩ |
| | | $T_j = 125^{\circ}\text{C}$ | | 53 | 62 | mΩ |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}, I_C = 1.2\text{ mA}$ | | 5.2 | 5.8 | 6.4 | V |
| I_{CES} | $V_{GE} = 0\text{ V}, V_{CE} = 1700\text{ V}, T_j = 25^{\circ}\text{C}$ | | | | 0.3 | mA |
| Q_G | $V_{GE} = -8\text{ V} \dots +15\text{ V}$ | | | 240 | | nC |
| R_{Gint} | $T_j = 25^{\circ}\text{C}$ | | | 32 | | Ω |
| $t_{d(on)}$ | $V_{CC} = 900\text{ V}$ $I_C = 20\text{ A}$ | $T_j = 125^{\circ}\text{C}$ | | 290 | | ns |
| t_r | $R_{G\ on} = 1\ \Omega$ | $T_j = 125^{\circ}\text{C}$ | | 40 | | ns |
| E_{on} | $R_{G\ off} = 1\ \Omega$ | $T_j = 125^{\circ}\text{C}$ | | 5.1 | | mJ |
| $t_{d(off)}$ | $di/dt_{on} = 580\text{ A}/\mu\text{s}$ | $T_j = 125^{\circ}\text{C}$ | | 690 | | ns |
| t_f | $di/dt_{off} = 120\text{ A}/\mu\text{s}$ $dv/dt = 4000\text{ V}/\mu\text{s}$ | $T_j = 125^{\circ}\text{C}$ | | 120 | | ns |
| E_{off} | $V_{GE} = +15/-15\text{ V}$ $L_s = 47\text{ nH}$ | $T_j = 125^{\circ}\text{C}$ | | 6.3 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 0.91 | | K/W |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.73 | | K/W |
| Inverse - Diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 40\text{ A}$ $V_{GE} = 0\text{ V}$ chipllevel | $T_j = 25^{\circ}\text{C}$ | | 2.00 | 2.38 | V |
| | | $T_j = 150^{\circ}\text{C}$ | | 2.14 | 2.56 | V |
| V_{F0} | chipllevel | $T_j = 25^{\circ}\text{C}$ | | 1.32 | 1.56 | V |
| | | $T_j = 150^{\circ}\text{C}$ | | 1.08 | 1.22 | V |
| r_F | chipllevel | $T_j = 25^{\circ}\text{C}$ | | 17 | 20 | mΩ |
| | | $T_j = 150^{\circ}\text{C}$ | | 27 | 33 | mΩ |
| I_{RRM} | $I_F = 20\text{ A}$ | $T_j = 125^{\circ}\text{C}$ | | 32.7 | | A |
| Q_{rr} | $di/dt_{off} = 620\text{ A}/\mu\text{s}$ $V_{GE} = -15\text{ V}$ | $T_j = 125^{\circ}\text{C}$ | | 8.7 | | μC |
| E_{rr} | $V_{CC} = 900\text{ V}$ | $T_j = 125^{\circ}\text{C}$ | | 4.9 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 1.14 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.95 | | K/W |
| Freewheeling - Diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 40\text{ A}$ $V_{GE} = 0\text{ V}$ chipllevel | $T_j = 25^{\circ}\text{C}$ | | 2.00 | 2.38 | V |
| | | $T_j = 150^{\circ}\text{C}$ | | 2.14 | 2.56 | V |
| V_{F0} | chipllevel | $T_j = 25^{\circ}\text{C}$ | | 1.32 | 1.56 | V |
| | | $T_j = 150^{\circ}\text{C}$ | | 1.08 | 1.22 | V |
| r_F | chipllevel | $T_j = 25^{\circ}\text{C}$ | | 17 | 20 | mΩ |
| | | $T_j = 150^{\circ}\text{C}$ | | 27 | 33 | mΩ |
| I_{RRM} | $I_F = 20\text{ A}$ | $T_j = 125^{\circ}\text{C}$ | | 32.7 | | A |
| Q_{rr} | $di/dt_{off} = 620\text{ A}/\mu\text{s}$ $V_{GE} = -15\text{ V}$ | $T_j = 125^{\circ}\text{C}$ | | 8.7 | | μC |
| E_{rr} | $V_{CC} = 900\text{ V}$ | $T_j = 125^{\circ}\text{C}$ | | 4.9 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 1.14 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.95 | | K/W |

SKiiP 24NAB176V1



MiniSKiiP® 2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter

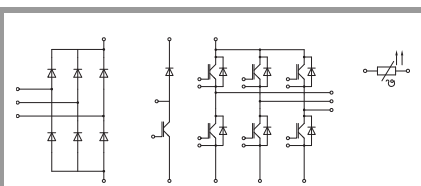
SKiiP 24NAB176V1

Features*

- Trench IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532
- NTC T-Sensor

Remarks

- Max. case temperature limited to $T_C=125^{\circ}\text{C}$
- Product reliability results valid for $T_j \leq 125^{\circ}\text{C}$ (recommended $T_{j,op} = -40 \dots +125^{\circ}\text{C}$)
- $I_{t(RMS)}$ limited to 20A for +B, B, -B, -DC/U, -DC/V, -DC/W power connectors
- The distance between terminals of temperature sensor and -DC/W is not sufficient for basic insulation
- The distance between terminals of +rect, +B and +DC not sufficient for basic insulation
- The distance between terminals of -B, -DC/U, DC/V and -DC/W not sufficient for basic insulation



NAB

| Characteristics | | | | | | |
|---------------------------|---|-----------------------------|------|------------------|------|------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Rectifier - Diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 41\text{ A}$ chipelevel | $T_j = 25^{\circ}\text{C}$ | | 1.19 | 1.45 | V |
| | | $T_j = 125^{\circ}\text{C}$ | | 1.17 | 1.42 | V |
| V_{F0} | chipelevel | $T_j = 25^{\circ}\text{C}$ | 0.6 | 0.87 | 1.10 | V |
| | | $T_j = 125^{\circ}\text{C}$ | | 0.75 | 0.97 | V |
| r_F | chipelevel | $T_j = 25^{\circ}\text{C}$ | | 7.9 | 8.7 | m Ω |
| | | $T_j = 125^{\circ}\text{C}$ | | 10 | 11 | m Ω |
| I_R | $T_j = 145^{\circ}\text{C}, V_{RRM}$ | | | | 1.1 | mA |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W/(mK)}$ | | | 1.32 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W/(mK)}$ | | | 1.12 | | K/W |
| Module | | | | | | |
| M_s | to heat sink | | 2 | | 2.5 | Nm |
| w | | | | 55 | | g |
| L_{CE} | | | | 31 | | nH |
| Temperature Sensor | | | | | | |
| R_{100} | $T_r=100^{\circ}\text{C}$ ($R_{25}=1000\Omega$) | | | 1670 \pm 3% | | Ω |
| $R_{(T)}$ | $R_{(T)}=1000\Omega[1+A(T-25^{\circ}\text{C})+B(T-25^{\circ}\text{C})^2]$, $A = 7.635 \cdot 10^{-3}\text{ }^{\circ}\text{C}^{-1}$, $B = 1.731 \cdot 10^{-5}\text{ }^{\circ}\text{C}^{-2}$ | | | | | |

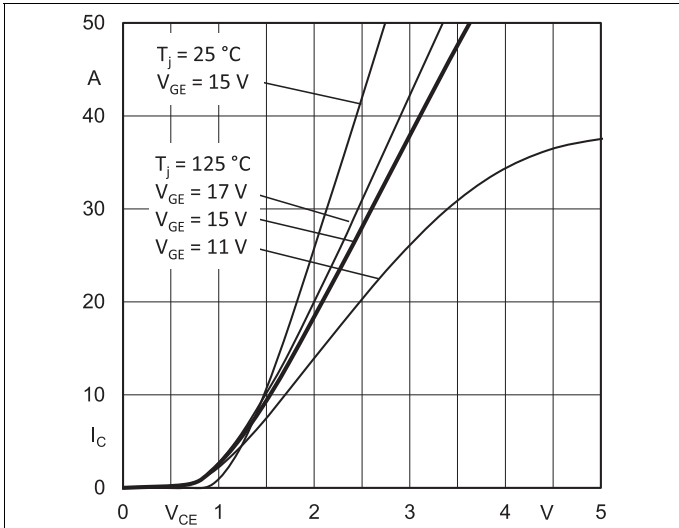


Fig. 1: Typ. output characteristic, inclusive $R_{CC'+EE'}$

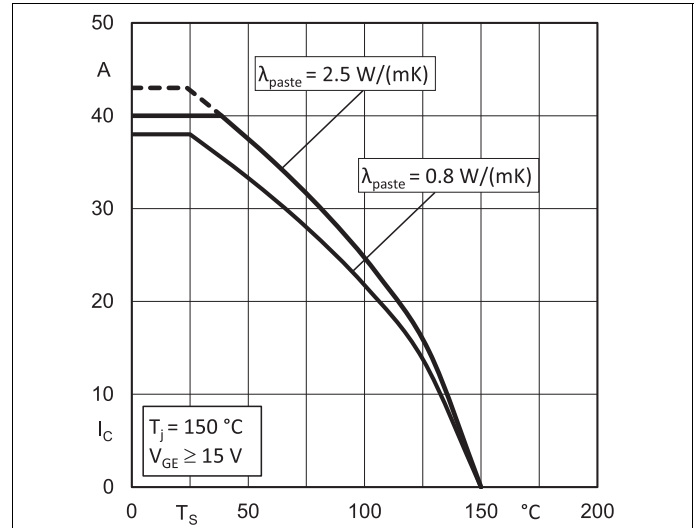


Fig. 2: Typ. rated current vs. temperature $I_C = f(T_s)$

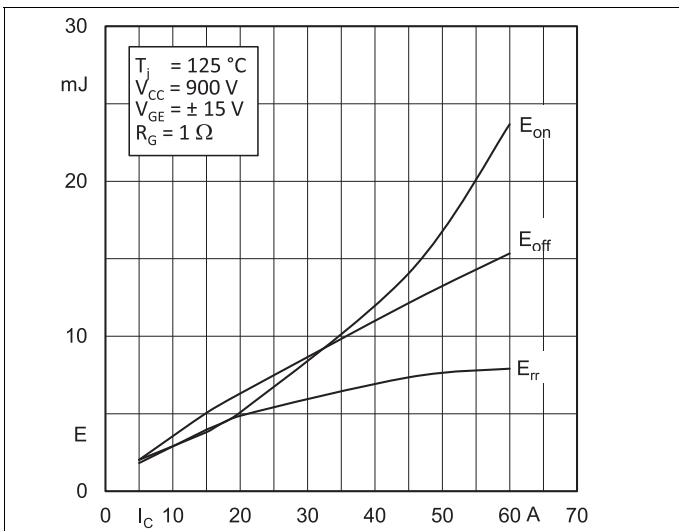


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

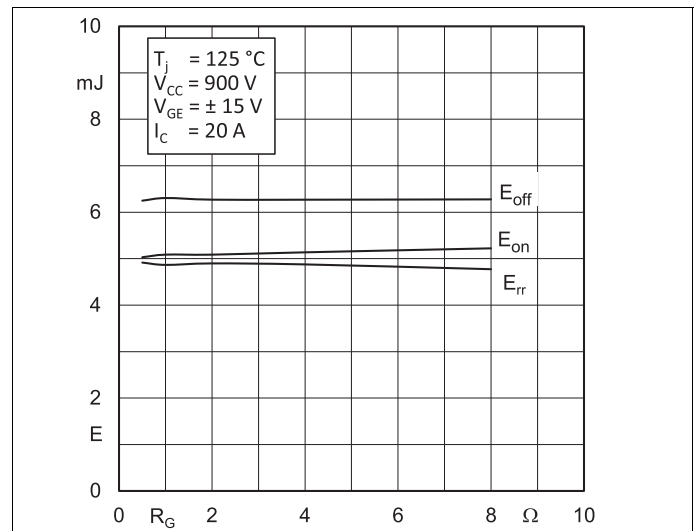


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

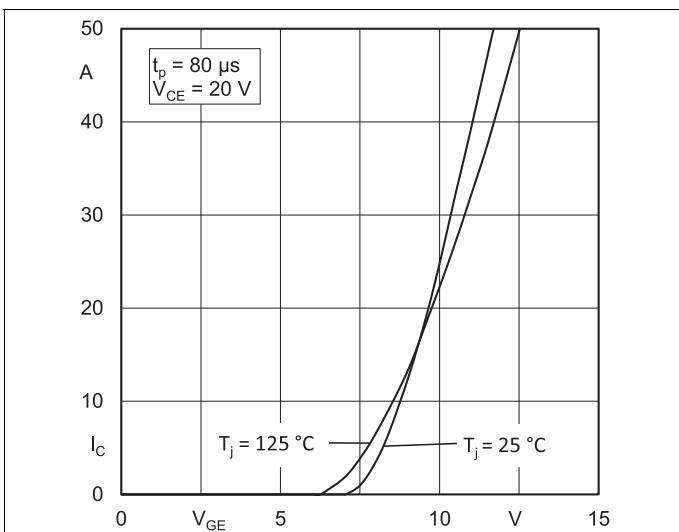


Fig. 5: Typ. transfer characteristic

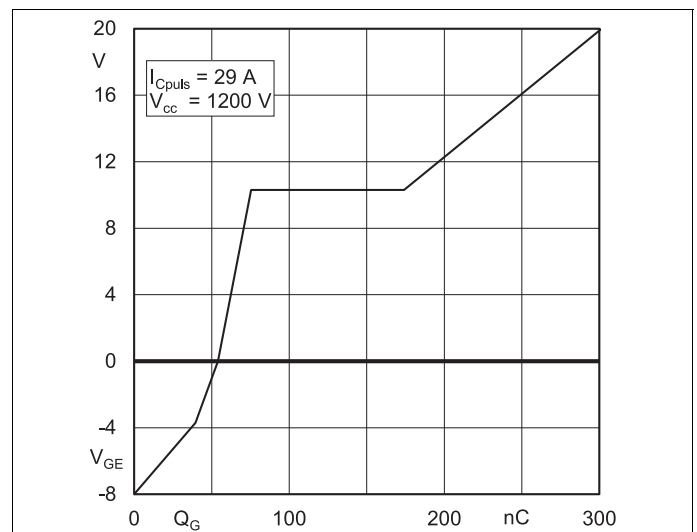


Fig. 6: Typ. gate charge characteristic

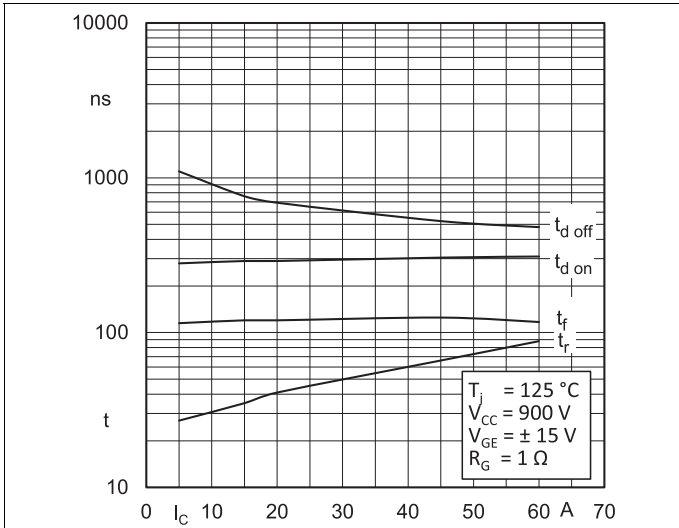


Fig. 7: Typ. switching times vs. I_C

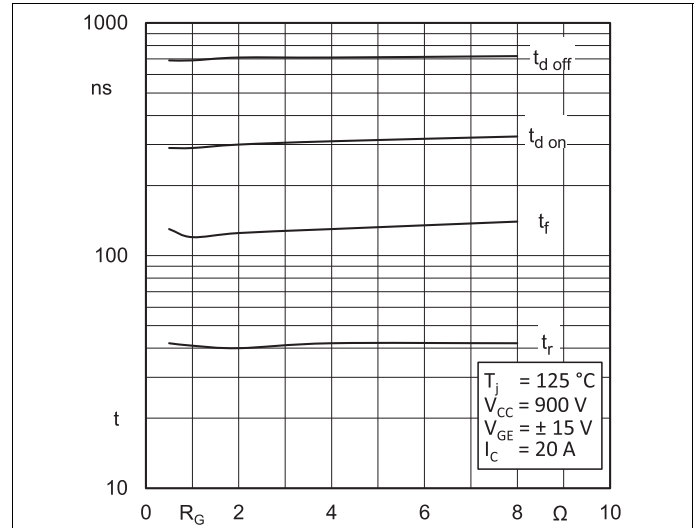


Fig. 8: Typ. switching times vs. gate resistor R_G

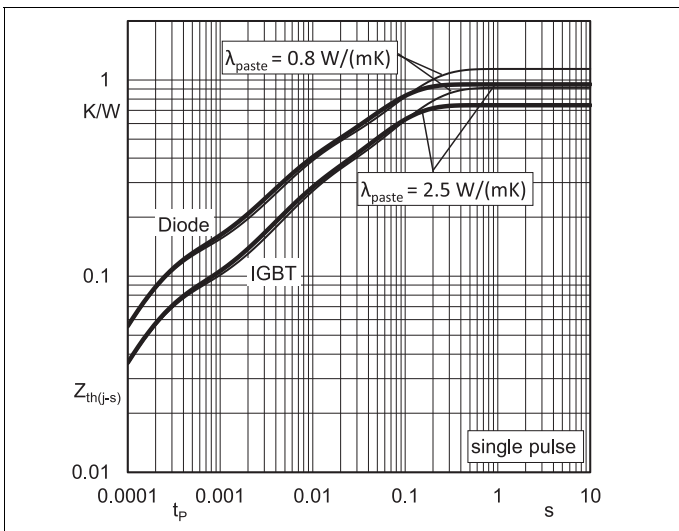


Fig. 9: Typ. transient thermal impedance

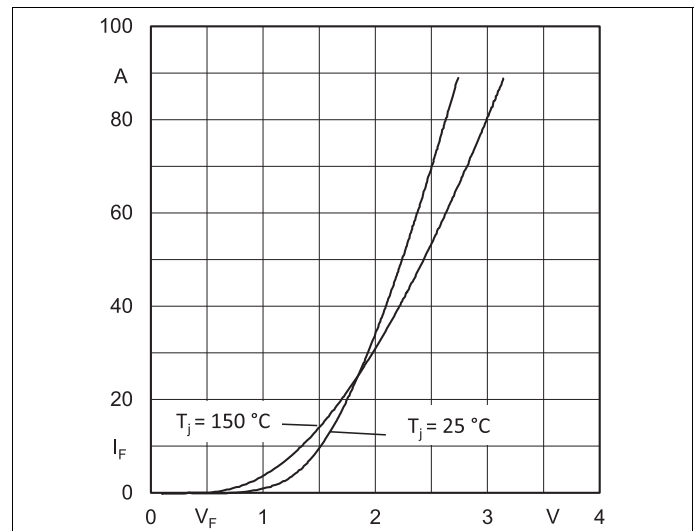


Fig. 10: Typ. CAL diode forward charact., incl. $R_{CC+EE'}$

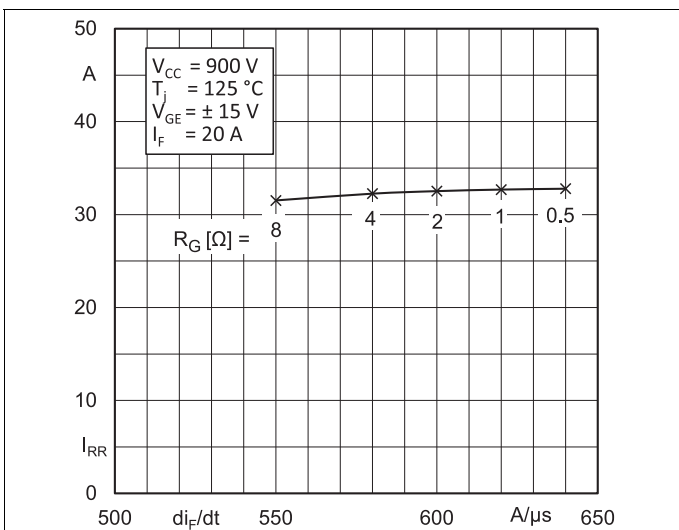


Fig. 11: Typ. CAL diode peak reverse recovery current

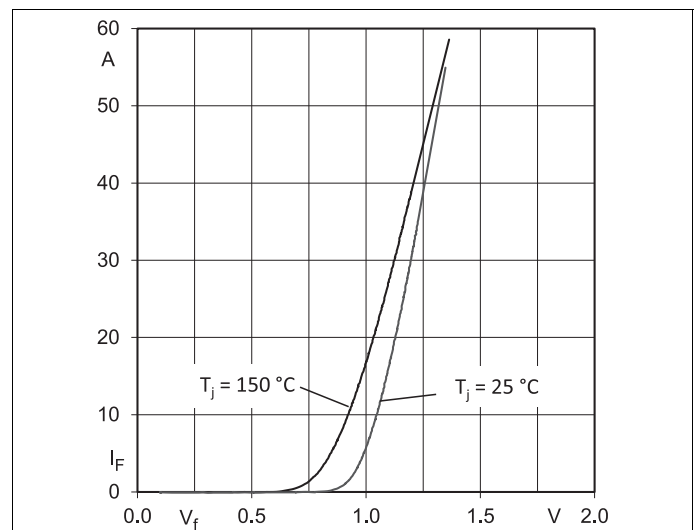
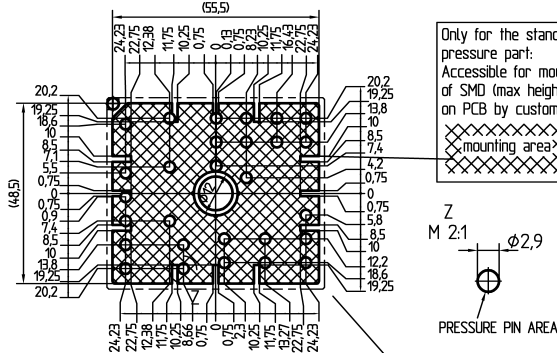
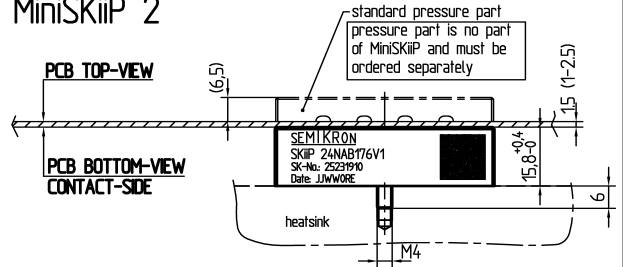


Fig. 12: Typ. input bridge forward characteristic incl. $R_{CC+EE'}$

PCB PCB TOP-VIEW



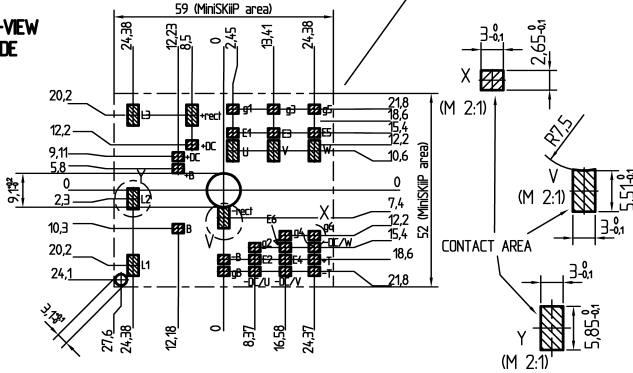
MiniSKiiP 2



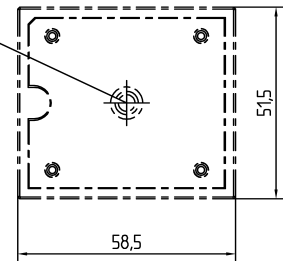
PCB TOP-VIEW



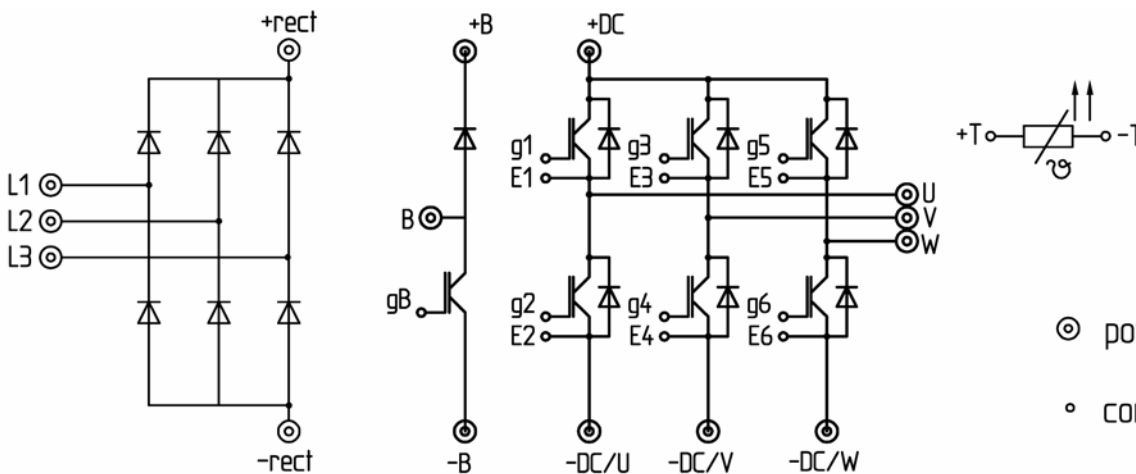
PCB BOTTOM-VIEW CONTACT-SIDE



For mounting please follow the assembly instruction



Pinout and Dimensions



⊙ power connector
○ control connector

Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

***IMPORTANT INFORMATION AND WARNINGS**

The specifications of SEMIKRON products may not be considered as guarantee or assurance of product characteristics ("Beschaffenheitsgarantie"). The specifications of SEMIKRON products describe only the usual characteristics of products to be expected in typical applications, which may still vary depending on the specific application. Therefore, products must be tested for the respective application in advance. Application adjustments may be necessary. The user of SEMIKRON products is responsible for the safety of their applications embedding SEMIKRON products and must take adequate safety measures to prevent the applications from causing a physical injury, fire or other problem if any of SEMIKRON products become faulty. The user is responsible to make sure that the application design is compliant with all applicable laws, regulations, norms and standards. Except as otherwise explicitly approved by SEMIKRON in a written document signed by authorized representatives of SEMIKRON, SEMIKRON products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury. No representation or warranty is given and no liability is assumed with respect to the accuracy, completeness and/or use of any information herein, including without limitation, warranties of non-infringement of intellectual property rights of any third party. SEMIKRON does not assume any liability arising out of the applications or use of any product; neither does it convey any license under its patent rights, copyrights, trade secrets or other intellectual property rights, nor the rights of others. SEMIKRON makes no representation or warranty of non-infringement or alleged non-infringement of intellectual property rights of any third party which may arise from applications. Due to technical requirements our products may contain dangerous substances. For information on the types in question please contact the nearest SEMIKRON sales office. This document supersedes and replaces all information previously supplied and may be superseded by updates. SEMIKRON reserves the right to make changes.